

PCN# 20230228008.1 Qualification of new Fab site (FFAB) using qualified Process Technology, Die Revision and additional Assembly BOM options for select devices Change Notification / Sample Request

Date: March 07, 2023 To: TOKYO ELECTRON DEVICE (DSTR) PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments (TI). The details of this change are on the following pages, and are in alignment with our standard product change notification (PCN) <u>process</u>.

TI requires acknowledgement of receipt of this notification within 30 days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If samples or additional data are required, requests must be received within 30 days of this notification, given that samples are not built ahead of the change.

The Proposed First Ship date in this PCN letter is the earliest possible date that customers could receive the changed material. It is our commitment that the changed device will not ship before that date. If samples are requested within the 30 day sample request window, customers will still have 30-days to complete their evaluation regardless of the proposed 1st ship date.

This particular PCN is related to TI's multiyear transition plan for our two remaining factories with 150-millimeter production (DFAB in Dallas, Texas, and SFAB in Sherman, Texas). DFAB will remain open, but will focus on 200-mm production, with a smaller set of technologies. SFAB will close no earlier than 2024 and no later than 2025. As referenced in the "reason for change" below, these changes are part of our multiyear plan to transition these products to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

For questions regarding this notice or to provide acknowledgement of this PCN, you may contact your local Field Sales Representative or the PCN Team (<u>PCN ww admin team@list.ti.com</u>). For sample requests or sample related questions, contact your local Field Sales Representative. As always, we thank you for your continued business.

PCN Team SC Business Services

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE

CUSTOMER PART NUMBER

OPA2277UA OPA2277UA/2K5 OPA2277UA/2K5E4 null null null

Technical details of this Product Change follow on the next page(s).

			202			PCN Date:			March 07, 2023
Title: Qualification of ne		of nev	ew Fab site (FFAB) using qualified Process Technology, Die Revision						
and additional Ass					ly BOM options for s	elect devic	es		
Customer Contact:			PCN Manager		Dept:			Quality Services	
_			: J	Jun 7, 2023		Sample requests accepted until:			Apr 7, 2023*
*Sample requests received after April 7, 2023 will not be supported.									
Change Type:									
Assembly Site				Assembly Process		Assembly Materials			
Design				Electrical Specification			Mechanical Specification		
Test Site			\boxtimes	Packing/Shipping/Labeling			Test Process		
□ Wafer Bump Site			Wafer Bump Material			Wafer Bump Process			
Wafer Fab Site		\square	Wafer Fab Materials		\square	Wafer	Fab Process		
·				Part number change		•			

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of a new fab & process technology (FFAB, BICOM3XHV) and assembly BOM options (MLA) for selected devices as listed below in the product affected section.

C	urrent Fab Site	9	Additional Fab Site		
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter
SFAB	JIBB	150 mm	FFAB	BICOM3XHV	200 mm

The die was also changed as a result of the process change.

Assembly BOM options are noted below:

	Current	Additional
Wire Type	1.2 mil Au	1.0 mil Cu
Mount compound	4205846	4147858
Mold compound	4209640	4226323
Die coat step	TI Malaysia	Bump Site

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-millimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings:

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
🛛 No Change	🛛 No Change	🛛 No Change	🛛 No Change

Changes to product identification resulting from this PCN:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	e Chip Site City	
SH-BIP-1	SHE	USA	Sherman	
FR-BIP-1	TID	DEU	Freising	
Die Rev:				
Current	New			
Die Rev [2P]	Die Rev [2P]			
D	Α			
	ing label (not actual prod			
TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 2Q: MSL 2 /260C/1 YEAR SEA MSL 1 /235C/UNLIM 03/ OPT: ITEM: 39 LBL: 5A (L)T0:1	G4 G4 L DT 29/04	uct label) 1P) SN74LS07NSR (Q) 2000 (D) 0336 311)LOT: 3959047MLA 4W) TKY (1T) 7523483S12 P) 2P) REV: (V) 0033317 20L) 650: SHE (21L) CCO-USA 22L) ASO: MLA (25L) ACO: MYS	>	
TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 2Q: MSL '2 /260C/1 YEAR SEA MSL 1 /235C/UNLIM 03/ OPT: ITEM: 39	G4 G4 L DT 29/04	1P) SN74LS07NSR (Q) 2000 (D) 0336 311)LOT: 3959047MLA 4W) TKY (1T) 7523483S12 P) 2P) REV: (V) 0033317 20L) GGO: GHE (21L) CCO-115A	>	
TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 2Q: MSL 2 /260C/1 YEAR SEA MSL 1 /235C/UNLIM 03/ OPT: ITEM: 39 LBL: 5A (L)T0:1	G4 G4 L DT 29/04	1P) SN74LS07NSR (Q) 2000 (D) 0336 311)LOT: 3959047MLA 4W) TKY (1T) 7523483S12 P) 2P) REV: (V) 0033317 20L) GGO: GHE (21L) CCO-115A	OPA2277UAG4	

For alternate parts with similar or improved performance, please visit the product page on <u>TI.com</u>

Qualification Report

Approve Date 01-Jul-2022

Qualification Results

Туре	Test Name / Condition	Duration	Qual Device: <u>OPA2277U</u>	QBS Process Reference: <u>OPA1637DGKR</u>	QBS Package Reference: <u>INA849D</u>		
HTOL	Life Test, 100C ^B	300 Hours	-	-	1/77/0		
HTOL	Life Test, 150C	300 Hours	-	3/231/0	-		
ELFR	Early Life Failure Rate, 150C	24 Hours	-	3/2400/1 ^A	-		
HBM	ESD - HBM	2000V	1/3/0	3/9/0	1/3/0		
HBM	ESD - HBM	2500V	1/3/0	3/9/0	1/3/0		
HBM	ESD - HBM	3000V	1/3/0	-	-		
HBM	ESD - HBM	4000V	1/3/0	-	-		
CDM	ESD - CDM	1000V	1/3/0	3/9/0	1/3/0		
CDM	ESD - CDM	1500V	1/3/0	3/9/0	1/3/0		
LU	Latch-up	Per JESD78, Class 2	1/6/0	3/18/0	1/6/0		
LU	Latch-up	Per JESD78, Class 1	1/6/0	3/30/0	1/6/0		
ED	Electrical Characterization	Per Datasheet Parameters	1/30/0	3/90/0	1/30/0		
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	-		
HTSL	High Temp Storage Bake 170C	420 Hours	-	3/231/0	3/231/0		
TC	Temperature Cycle, -65/150C	500 Cycles	1/77/0	3/231/0	3/231/0		
THB	Biased Temperature and Humidity, 85C/85%RH	1000 Hours	-	-	3/231/0		
UHAST	Unbiased HAST 130C/85%RH	96 Hours	-	3/231/0	3/231/0		

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

A - Crack at die corner under bond pad. Not stress related. See attached 8D in qualification plan.

B -Tj of device at 150C

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours - The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free (SMT) and Green

For questions regarding this notice, e-mails can be sent to the contact below or your local Field Sales Representative.

Location	E-Mail			
WW Change Management Team	<u>PCN ww admin team@list.ti.com</u>			

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